

TOSHIBA GTR Module Silicon N Channel IGBT

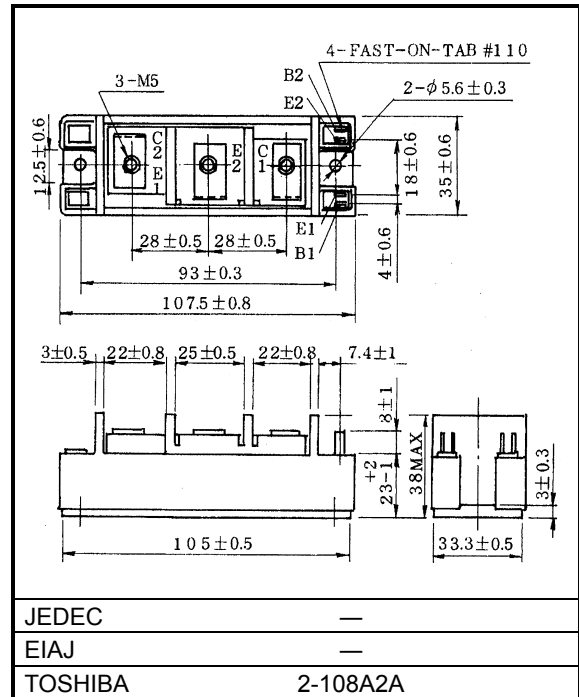
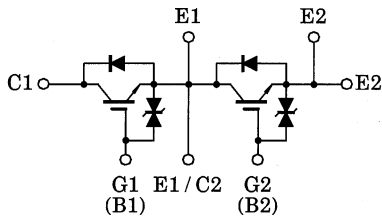
MG100Q2YS40

Unit: mm

High Power Switching applications
Motor Control Applications

- High input impedance
- High speed : $t_f = 0.5\mu\text{s}$ (Max)
 $t_{rr} = 0.5\mu\text{s}$ (Max)
- Low saturation voltage
: $V_{CE}(\text{sat}) = 4.0\text{V}$ (Max)
- Enhancement-mode
- Includes a complete half bridge in one package.
- The electrodes are isolated from case.

Equivalent Circuit

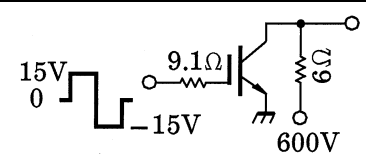


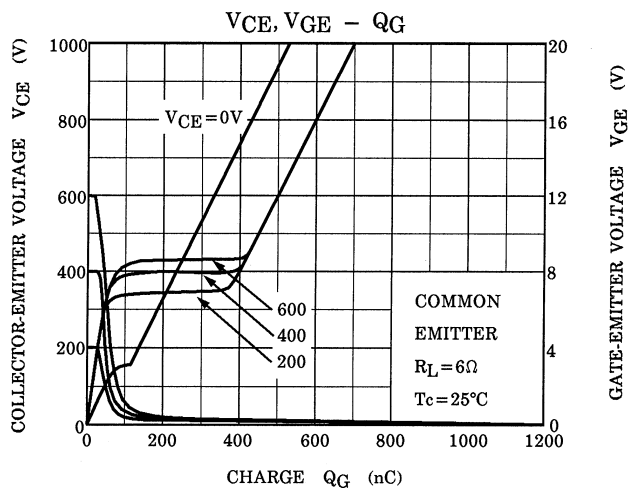
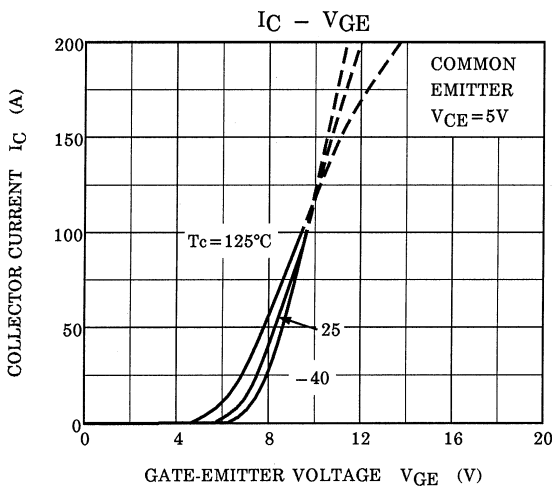
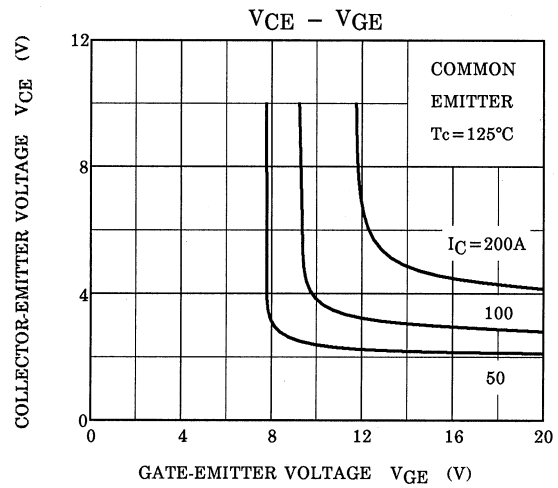
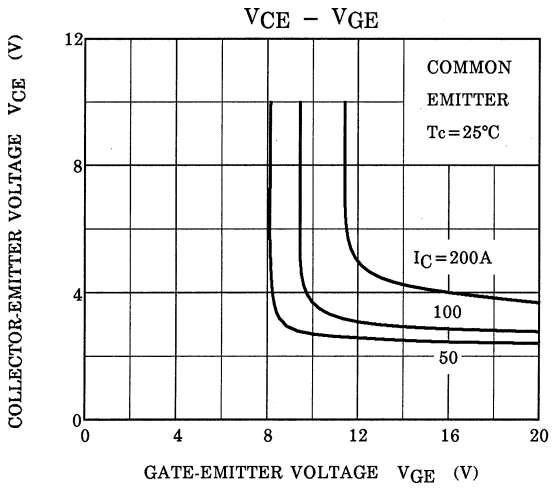
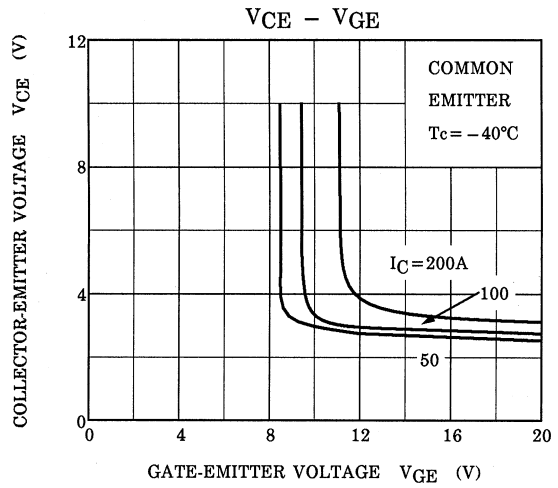
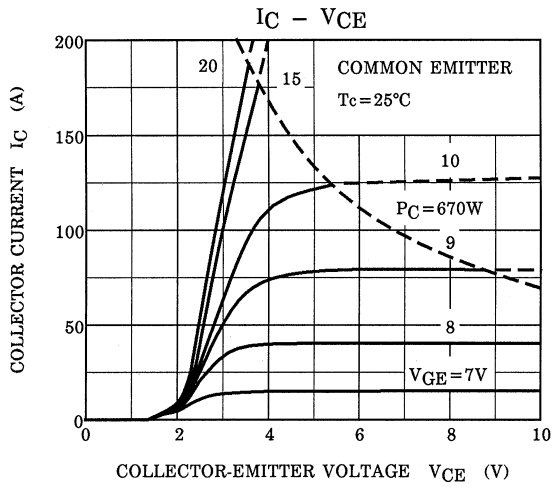
Weight: 240g

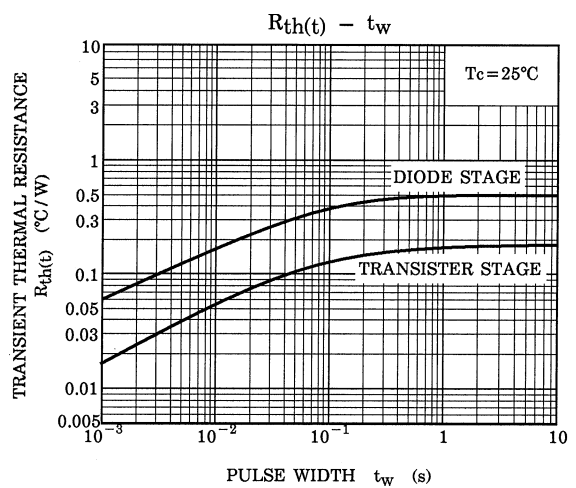
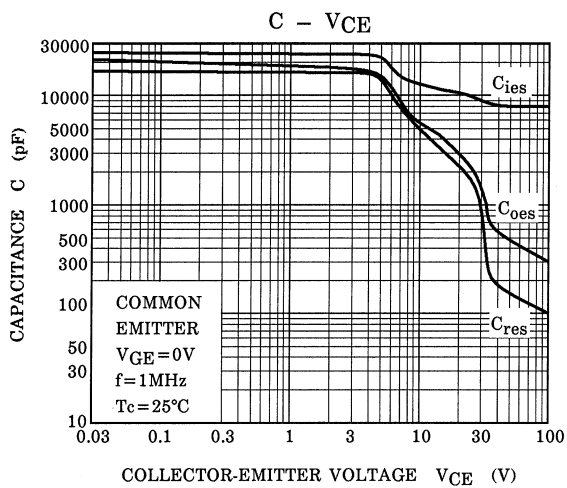
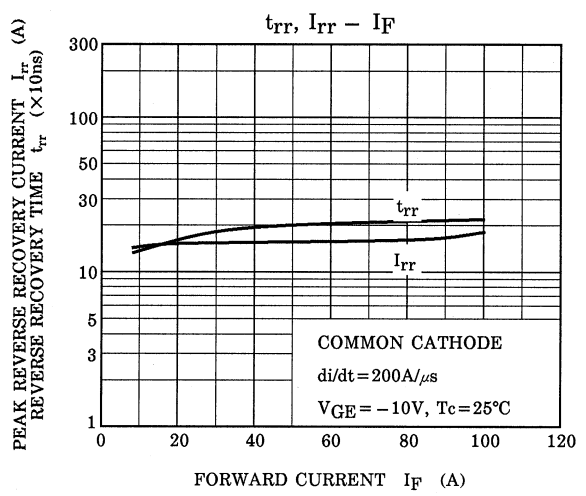
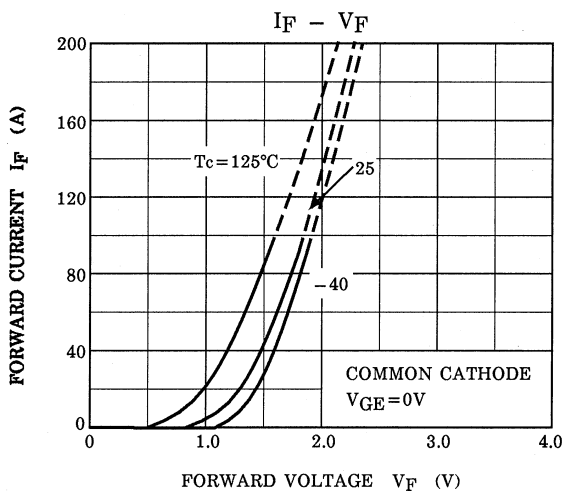
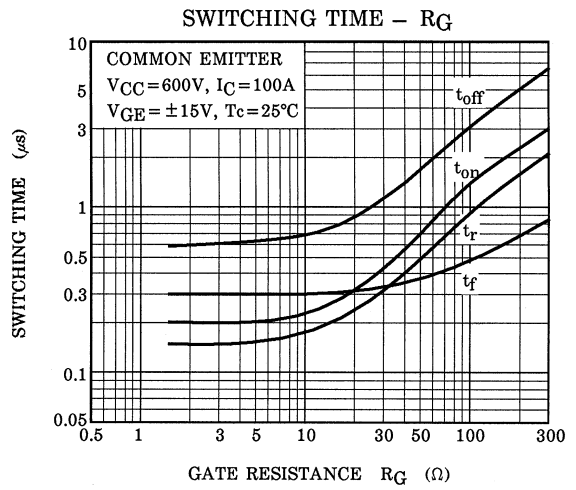
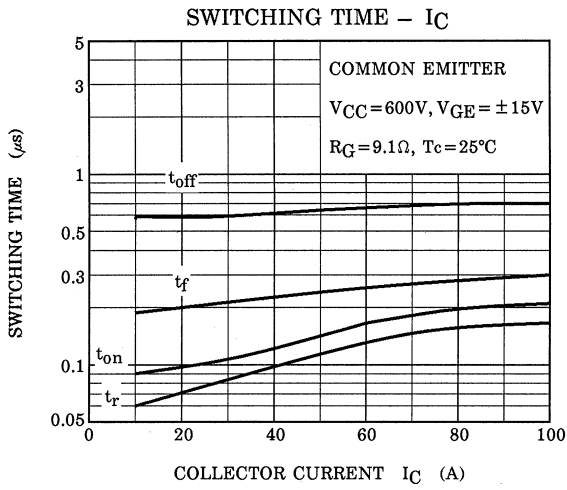
Maximum Ratings ($T_a = 25^\circ\text{C}$)

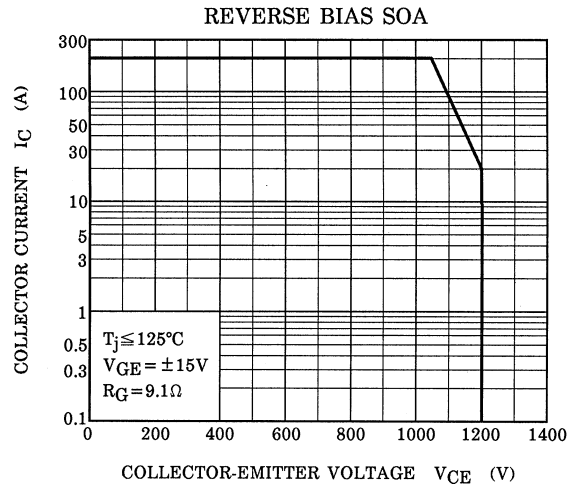
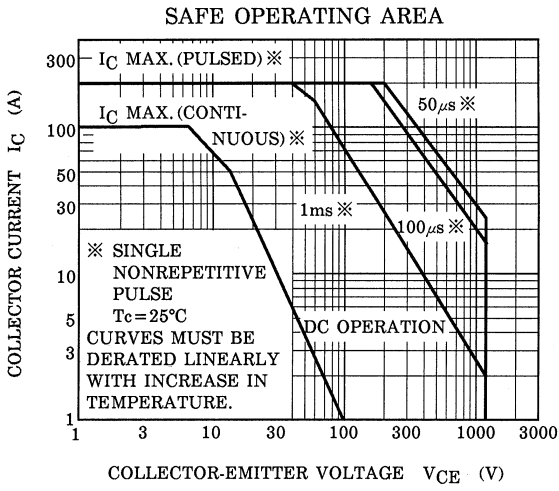
Characteristic	Symbol	Rating	Unit
Collector-emitter voltage	V_{CES}	1200	V
Gate-emitter voltage	V_{GES}	± 20	V
Collector current	DC	I_C	100
	1ms	I_{CP}	200
Forward current	DC	I_F	100
	1ms	I_{FM}	200
Collector power dissipation ($T_c = 25^\circ\text{C}$)	P_C	670	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	$-40 \sim 125$	$^\circ\text{C}$
Isolation voltage	V_{Isol}	2500 (AC 1 min.)	V
Screw torque (Terminal / mounting)	—	3 / 3	N·m

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	± 10	μA
Collector cut-off current		I_{CES}	$V_{CE} = 1200V, V_{GE} = 0$	—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE (off)}$	$I_C = 100mA, V_{CE} = 5V$	3.0	—	6.0	V
Collector-emitter saturation voltage		$V_{CE (sat)}$	$I_C = 100A, V_{GE} = 15V$	—	3.0	4.0	V
Input capacitance		C_{ies}	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	12000	—	pF
Switching time	Rise time	t_r		—	0.3	0.6	μs
	Turn-on time	t_{on}		—	0.4	0.8	
	Fall time	t_f		—	0.2	0.5	
	Turn-off time	t_{off}		—	0.8	1.5	
Forward voltage		V_F	$I_F = 100A, V_{GE} = 0$	—	2.0	3.0	V
Reverse recovery time		t_{rr}	$I_F = 100A, V_{GE} = -10V$ $di / dt = 200A / \mu s$	—	0.25	0.5	μs
Thermal resistance		$R_{th (j-c)}$	Transistor	—	—	0.19	$^{\circ}C / W$
			Diode	—	—	0.5	







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